

SOLUTIONS OF TUT. SHEET NO. 7

Q1 & Q2: SOLUTION

Q1

$A_{mid} = 10, f_L = 20\text{Hz}$ and $f_H = 20\text{kHz}$

$$A_v (F = 7.5\text{Hz}) = \frac{(10)^n}{[1 + (20/7.5)^2]^{n/2}}$$

$$= \frac{152}{(10)^n}$$

$$A_v (F = 200\text{kHz}) = \frac{(10)^n}{[1 + (200\text{K}/20\text{K})^2]^{n/2}}$$

$$= \underline{0.98}$$

Q2

$f_L = 20\text{Hz}, f_H = 20\text{kHz}$

(i) $f_L^* = \frac{f_L}{\sqrt{2^{1/n} - 1}}$

$$\therefore f_L = \frac{f_L^* \sqrt{2^{1/n} - 1}}{f_L^*} = 20 \times \sqrt{2^{1/3} - 1} = 10.196\text{Hz}$$

(ii) $f_H^* = f_H \sqrt{2^{1/n} - 1}$

$$\therefore f_H = \frac{f_H^*}{\sqrt{2^{1/n} - 1}} = \frac{20 \times 10^3}{\sqrt{2^{1/3} - 1}} = \frac{20 \times 10^3}{\sqrt{2^{1/3} - 1}} = 39.23\text{kHz}$$

(iii) Bandwidth $f_H - f_L = 39.23 \times 10^3 - 10.196 = 39.218\text{kHz}$

Q3: SOLUTION

Solution: We know that the overall voltage gain in dB of the three-stage amplifier is given as

$$A_{dB} = A_{dB1} + A_{dB2} + A_{dB3}$$

But, we are given the voltage gains of the individual stages as ratios. So, we should first find the gains of the individual stages in decibels. Thus

$$A_{dB1} = 20 \log_{10} 30 = 29.54 \text{ dB}$$

$$A_{dB2} = 20 \log_{10} 50 = 33.98 \text{ dB}$$

$$A_{dB3} = 20 \log_{10} 80 = 38.06 \text{ dB}$$

Therefore

$$A_{dB} = 29.54 + 33.98 + 38.06 = \mathbf{101.58 \text{ dB}}$$

Alternatively, we could have determined A_{dB} as follows: The overall voltage gain is

$$\begin{aligned} A &= A_1 \times A_2 \times A_3 \\ &= 30 \times 50 \times 80 = 120\,000 \end{aligned}$$

Therefore, the overall voltage gain in dB is

$$A_{dB} = 20 \log_{10} 120\,000 = \mathbf{101.58 \text{ dB}}$$

Q4: SOLUTION

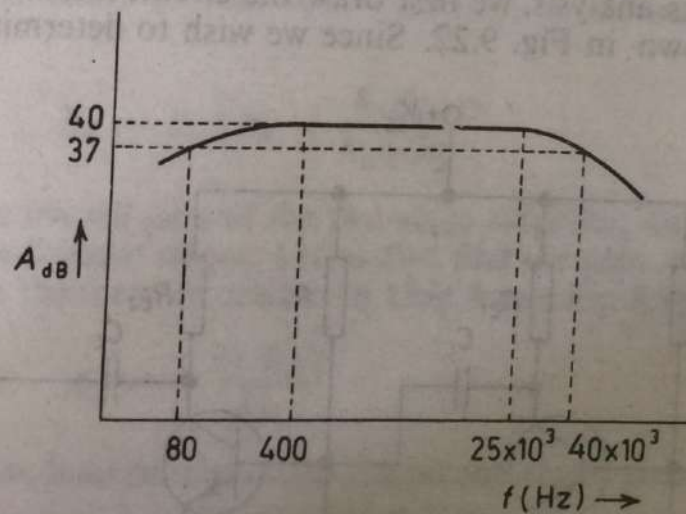
Solution: The gain in dB is

$$A_{dB} = 20 \log_{10} A = 20 \log_{10} 100 = 40 \text{ dB}$$

This is the mid-band gain. The gain at cut-off frequencies is 3 dB less than the mid-band gain, i.e.

$$(A_{dB}) \text{ (at cut-off frequencies)} = 40 - 3 = 37 \text{ dB}$$

The plot of the frequency response curve is given in Fig. 9.20.



Q5: SOLUTION

Solution a. From Eq. (12-33) we have

$$f_L = \frac{1}{2\pi(R_o' + R_i')C_b} \leq 10$$

or

$$C_b \geq \frac{1}{62.8(R_o' + R_i')}$$

Since $R_i' = 1 \text{ M}$ and $R_o' < R_y = 1 \text{ K}$, then $R_o' + R_i' \approx 1 \text{ M}$ and $C_b \geq 0.016 \mu\text{F}$.

b. From Eq. (8-35) we find for a transistor $R_o \geq 1/h_{oe} \approx 40 \text{ K}$, and hence $R_o' \approx R_o = 1 \text{ K}$. If we assume that $R_b \gg R_i = 1 \text{ K}$, then $R_i' \approx 1 \text{ K}$. Hence

$$C_b \geq \frac{1}{(62.8)(2 \times 10^3)} \text{ F} = 8.0 \mu\text{F}$$